

10/516687

DT15 Rec'd 12/7/04 06 DEC 2004

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: **Hiroshi YOSHIDA et al.**

Serial No.: **Not yet assigned**

(§371 of international application No. PCT/JP03/07161)

Filed: **December 6, 2004**

For: **FERROMAGNETIC GROUP IV-BASED SEMICONDUCTOR OR
FERROMAGNETIC GROUP III-V-BASED OR GROUP II-VI-BASED
COMPOUND SEMICONDUCTOR, AND METHOD FOR ADJUSTING
FERROMAGNETIC CHARACTERISTICS THEREOF**

Attorney Docket No.: **042880**

Customer Number: **38834**

PRELIMINARY AMENDMENT

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

December 6, 2004

Sir:

Prior to calculation of the filing fee and examination of this application, please amend the above-identified application as follows:

Amendments to the Claims are reflected in the listing of claims that begins on page 2 of this paper.

Remarks begin on page 6 of this paper.